MARKING

Z86M •



TinyLogic UHS Two-Input Exclusive-OR Gate

NC7SZ86

Description

The NC7SZ86 is a single two-input exclusive–OR gate from **onsemi**'s Ultra–High Speed (UHS) series of TinyLogic. The device is fabricated with advanced CMOS technology to achieve ultra–high speed with high output drive while maintaining low static power dissipation over a broad VCC operating range. The device is specified to operate over the 1.65 V to 5.5 V $V_{\rm CC}$ operating range. The inputs and output are high impedance when $V_{\rm CC}$ is 0 V. Inputs tolerate voltages up to 5.5 V, independent of $V_{\rm CC}$ operating voltage.

Features

- Ultra–High Speed: t_{PD} = 2.9 ns (Typical) into 50 pF at 5 V V_{CC}
- High Output Drive: ±24 mA at 3 V V_{CC}
- Broad V_{CC} Operating Range: 1.65 V to 5.5 V
- Matches Performance of LCX Operated at 3.3 V V_{CC}
- Power Down High-Impedance Inputs / Outputs
- Over-Voltage Tolerance Inputs Facilitate 5 V to 3 V Translation
- Proprietary Noise / EMI Reduction Circuitry
- Ultra-Small MicroPakTM Packages
- Space-Saving SOT23-5, SC-74A and SC-88A Packages
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

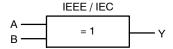


Figure 1. Logic Symbol

DIAGRAMS SIP6 взкк CASE 127EB XYZ Pin 1 UDFN6 В3КК CASE 517DP XYZ Pin 1 7Z86M = SC-74A CASE 318BQ 0 SOT23-5 7Z86 M CASE 527AH

B3, 7Z86, Z86 = Specific Device Code

KK = 2-Digit Lot Run Traceability Code
XY = 2-Digit Date Code Format
Z = Assembly Plant Code
M = Data Code

SC-88A CASE 419A-02

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 6 of this data sheet.

Pin Configurations

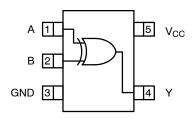


Figure 2. SOT23-5,SC-88A and SC-74A (Top View)

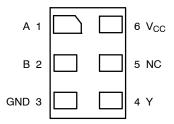


Figure 3. MicroPak (Top Through View)

PIN DEFINITIONS

Pin # SC-88A / SC74A/SOT23-5	Pin # MicroPak	Name	Description
1	1	Α	Input
2	2	В	Input
3	3	GND	Ground
4	4	Υ	Output
5	6	V _{CC}	Supply Voltage
	5	NC	No Connect

FUNCTION TABLE

Inp	Output	
Α	В	Υ
L	L	L
L	Н	Н
Н	L	Н
Н	Н	L

H = HIGH Logic Level L = LOW Logic Level

ABSOLUTE MAXIMUM RATINGS

Symbol	Parame	Parameter		Max	Unit
V _{CC}	Supply Voltage		-0.5	6.5	V
V _{IN}	DC Input Voltage		-0.5	6.5	V
V _{OUT}	DC Output Voltage		-0.5	6.5	V
I _{IK}	DC Input Diode Current	V _{IN} < 0 V	=	-50	mA
I _{OK}	DC Output Diode Current	V _{OUT} < 0 V	=	-50	mA
I _{OUT}	DC Output Current		=	±50	mA
I _{CC} or I _{GND}	DC V _{CC} or Ground Current		=	±50	mA
T _{STG}	Storage Temperature Range		-65	+150	°C
TJ	Junction Temperature Under Bias		=	+150	°C
TL	Junction Lead Temperature (Solde	ering, 10 Seconds)	=	+260	°C
P_{D}	Power Dissipation in Still Air	SC-74A / SOT23-5	=	390	mW
		SC-88A	=	332	
		MicroPak-6	-	812	
		MicroPak2™-6	-	812	
ESD	Human Body Model, JEDEC: JESD22-A114		-	2000	V
	Charge Device Model, JEDEC: JE	SD22-C101	=	1000	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	Supply Voltage Operating		1.65	5.5	V
	Supply Voltage Data Retention		1.5	5.5	
V _{IN}	Input Voltage		0	5.5	V
V _{OUT}	Output Voltage		0	V _{CC}	V
T _A	Operating Temperature		-40	+85	°C
t _r , t _f	Input Rise and Fall Times	V _{CC} = 1.8 V, 2.5 V ±0.2 V	0	20	ns/V
		V _{CC} = 3.3 V ±0.3 V	0	10	
		V _{CC} = 5.0 V ±0.5 V	0	5	
$\theta_{\sf JA}$	Thermal Resistance	SC-74A / SOT23-5	-	320	°C/W
		SC-88A	-	377	
		MicroPak-6	-	154	
		MicroPak2-6	-	154	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

1. Unused inputs must be held HIGH or LOW. They may not float.

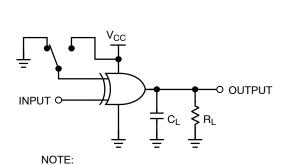
DC ELECTICAL CHARACTERISTICS

				T,	<u>1</u> = +25°	°C	T _A = -40	to +85°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Min	Тур	Max	Min	Max	Unit
V _{IH}	HIGH Level Input Voltage	1.65 to 1.95		0.65 V _{CC}	-	-	0.65 V _{CC}	-	V
		2.30 to 5.50		0.70 V _{CC}	-	-	0.70 V _{CC}	-	
V_{IL}	LOW Level Input Voltage	1.65 to 1.95		-	-	0.35 V _{CC}	-	0.35 V _{CC}	V
		2.30 to 5.50		-	-	0.30 V _{CC}	-	0.30 V _{CC}	
V _{OH}	HIGH Level Output Voltage	1.65	V _{IN} = V _{IH} or V _{IL}	1.55	1.65	-	1.55	-	V
		1.80	I _{OH} = -100 μA	1.70	1.80	-	1.70	-	
		2.30		2.20	2.30	-	2.20	_	
		3.00		2.90	3.00	-	2.90	_	
		4.50		4.40	4.50	-	4.40	-	
		1.65	I _{OH} = -4 mA	1.29	1.52	-	1.29	-	
		2.30	I _{OH} = -8 mA	1.90	2.15	-	1.90	-	
		3.00	I _{OH} = -16 mA	2.40	2.80	-	2.40	-	
		3.00	I _{OH} = -24 mA	2.30	2.68	-	2.30	_	
		4.50	I _{OH} = -32 mA	3.80	4.20	-	3.80	_	
V _{OL}	LOW Level Output Voltage	1.65	V _{IN} = V _{IH} or V _{IL}	-	0.00	0.10	-	0.10	V
		1.80	I _{OL} = 100 μA	-	0.00	0.10	-	0.10	
		2.30		_	0.00	0.10	-	0.10	
		3.00		-	0.00	0.10	-	0.10	
		4.50		-	0.00	0.10	-	0.10	
		1.65	I _{OL} = 4 mA	-	0.80	0.24	-	0.24	
		2.30	I _{OL} = 8 mA	-	0.10	0.30	-	0.30	
		3.00	I _{OL} = 16 mA	-	0.15	0.40	-	0.40	
		3.00	I _{OL} = 24 mA	-	0.22	0.55	-	0.55	1
		4.50	I _{OL} = 32 mA	-	0.22	0.55	-	0.55]
I _{IN}	Input Leakage Current	1.65 to 5.5	V _{IN} = 5.5 V, GND	-	_	±1	-	±10	μΑ
I _{OFF}	Power Off Leakage Current	0	V _{IN} or V _{OUT} = 5.5 V	-	-	1	-	10	μΑ
I _{CC}	Quiescent Supply Current	1.65 to 5.5	V _{IN} = 5.5 V, GND	-	-	2	-	20	μΑ

AC ELECTRICAL CHARACTERISTICS

				7	Γ _A = +25°C	;	T _A = -40	to +85°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Min	Тур	Max	Min	Max	Unit
t _{PLH} , t _{PHL}	PLH, tPHL Propagation Delay (Figure 4, 5)	1.65	C _L = 15 pF,	-	6.9	13.8	-	14.5	ns
		1.80	$R_L = 1 M\Omega$	-	5.7	11.5	_	12.0	
		2.50 ±0.20		-	3.8	8.0	_	8.5	
		3.30 ±0.30		-	3.0	5.7	_	6.0	
		5.00 ±0.50		-	2.4	5.0	_	5.4	
		3.30 ±0.30	C _L = 50 pF,	-	3.5	6.2	_	6.5	
		5.00 ±0.50	$R_L = 500 \Omega$	-	2.9	5.4	_	5.8	
C _{IN}	Input Capacitance	0.00		-	4	_	_	-	pF
C _{PD}	C _{PD} Power Dissipation Capacitance	3.30		_	25	-	_	-	pF
	(Note 2) (Figure 6)	5.00		_	31	_	_	-	

C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. C_{PD} is related to I_{CCD} dynamic operating current by the expression:
 I_{CCD} = (C_{PD}) (V_{CC}) (f_{IN}) + (I_{CC}static).



3. C_L includes load and stray capacitance; Input PRR = 10 MHz; t_W = 500 ns

Figure 4. AC Test Circuit

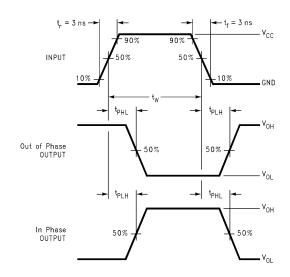
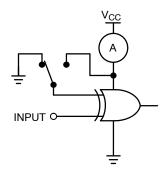


Figure 5. AC Waveforms



NOTE:

4. Input = AC Waveform; $t_r = t_f = 1.8 \text{ ns}$; PRR = 10 MHz; Duty Cycle = 50%.

Figure 6. I_{CCD} Test Circuit

ORDERING INFORMATION

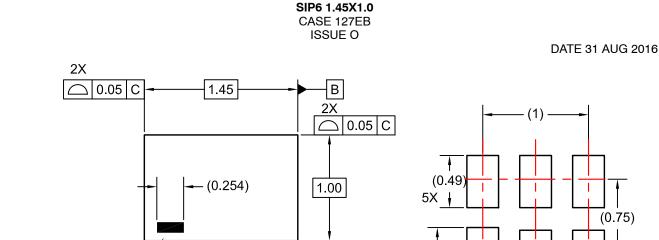
Part Number	Top Mark	Package	Shipping [†]
NC7SZ86M5X	7Z86	SC-74A	3000 / Tape & Reel
NC7SZ86M5X-L22090	7Z86	SOT23-5	3000 / Tape & Reel
NC7SZ86P5X	Z86	SC-88A	3000 / Tape & Reel
NC7SZ86L6X	B3	SIP6, MicroPak	5000 / Tape & Reel
NC7SZ86L6X-L22175	B3	SIP6, MicroPak	5000 / Tape & Reel
NC7SZ86FHX	B3	UDFN6, MicroPak2	5000 / Tape & Reel
NC7SZ86FHX-L22175	B3	UDFN6, MicroPak2	5000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MicroPak and MicroPak2 are trademarks of Semiconductor Components Industries, LLC (SCILLC) or its subsidiaries in the United States and/or other countries.

PIN 1 IDENTIFIER

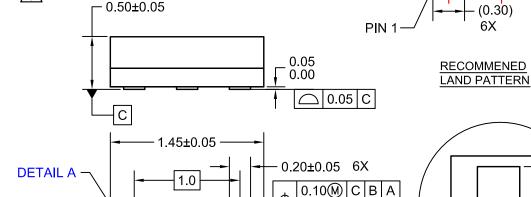
- 0.35±0.05



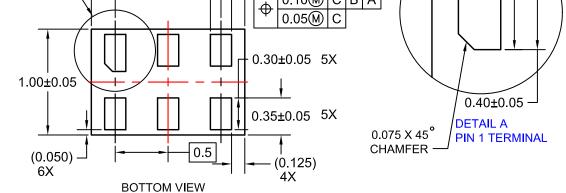
Α

(0.52)

1X <u>1</u>



TOP VIEW



NOTES:

- 1. CONFORMS TO JEDEC STANDARD MO-252 VARIATION UAAD
- 2. DIMENSIONS ARE IN MILLIMETERS
- 3. DRAWING CONFORMS TO ASME Y14.5M-2009
 4. PIN ONE IDENTIFIER IS 2X LENGTH OF ANY
- - OTHER LINE IN THE MARK CODE LAYOUT.

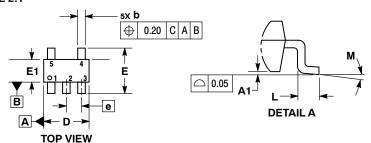
DOCUMENT NUMBER:	98AON13590G	Electronic versions are uncontrolled except when accessed directly from Printed versions are uncontrolled except when stamped "CONTROLLED	
DESCRIPTION:	SIP6 1.45X1.0		PAGE 1 OF 1

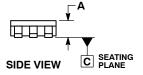
ON Semiconductor and un are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

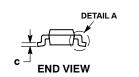




DATE 18 JAN 2018





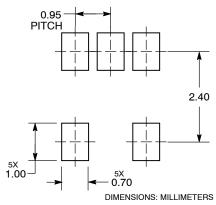


NOTES:

- IES:
 DIMENSIONING AND TOLERANCING PER ASME
 Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH
 THICKNESS. MINIMUM LEAD THICKNESS IS THE
 MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE.

	MILLIN	MILLIMETERS		
DIM	MIN	MAX		
Α	0.90	1.10		
A1	0.01	0.10		
b	0.25	0.50		
С	0.10	0.26		
D	2.85	3.15		
E	2.50	3.00		
E1	1.35	1.65		
е	0.95 BSC			
L	0.20	0.60		
M	0 °	10°		

RECOMMENDED SOLDERING FOOTPRINT*



^{*}For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

Μ = Date Code = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ", may or may not be present. Some products may not follow the Generic Marking.

DOCUMENT NUMBER:	98AON66279G	Electronic versions are uncontrolled except when accessed directly from Printed versions are uncontrolled except when stamped "CONTROLLED (
DESCRIPTION:	SC-74A		PAGE 1 OF 1

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. **onsemi** does not convey any license under its patent rights nor the rights of others.





SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE M

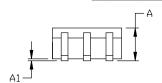
DATE 11 APR 2023

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETERS
- 419A-01 DBSDLETE. NEW STANDARD 419A-02
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

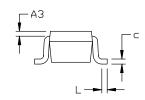
DIM	MILLIMETERS		
الملتط	MIN.	N□M.	MAX.
А	0.80	0.95	1.10
A1			0.10
A3	0,20 REF		
b	0.10	0.20	0.30
С	0.10		0.25
D	1.80	2.00	2,20
Е	2.00	2.10	2.20
E1	1.15	1.25	1.35
е	0.65 BSC		
L	0.10	0.15	0.30

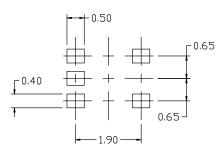
е Ε1 0



5X b

◆ 0.2 M B M





RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

STYLE 9:

STYLE 1:
PIN 1. BASE
EMITTER
3. BASE
COLLECTOR
COLLECTOR

STYLE 2: PIN 1. ANODE 2. EMITTER 3. BASE 4. COLLECTOR CATHODE

STYLE 3: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. CATHODE 1 STYLE 8:

PIN 1. CATHODE 2. COLLECTOR 3. N/C

4. BASE

STYLE 4: PIN 1. SOURCE 1 2. DRAIN 1/2 3 SOURCE 1 4. GATE 1 5. GATE 2

PIN 1. ANODE 2. CATHODE

3. ANODE 4. ANODE

STYLE 5: PIN 1. CATHODE 2. COMMON ANODE 3. CATHODE 2 4. CATHODE 3 5. CATHODE 4

Note: Please refer to datasheet for style callout. If style type is not called

out in the datasheet refer to the device

٥.	LIVILLELL
4.	COLLECTOR
5.	COLLECTOR 2

DOCUMENT NUMBER:

2. BASE 2

STYLE 6:

PIN 1. EMITTER 2 2. EMITTER 3. BASE 4. COLLECTOR /BASE 1 5. COLLECTOR

STYLE 7:

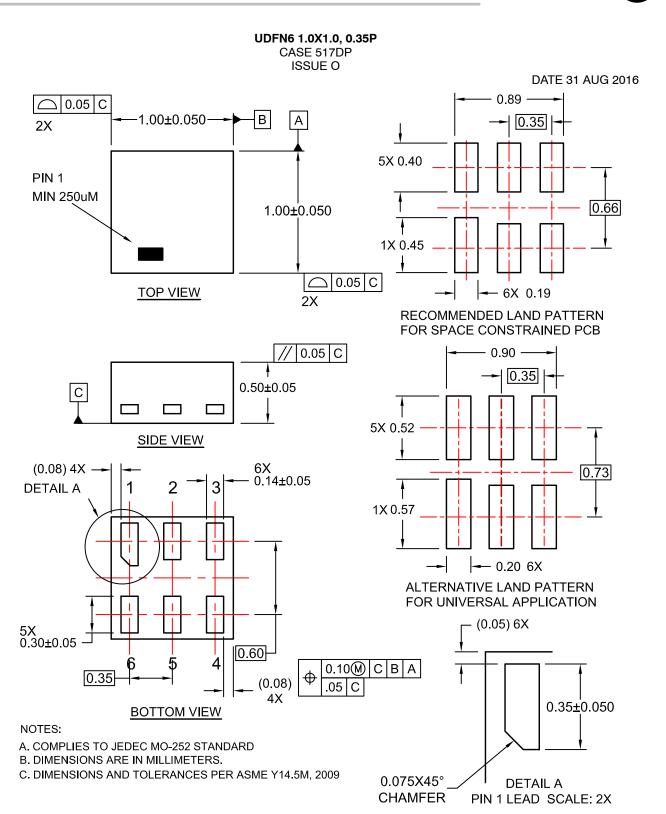
PIN 1. BASE

98ASB42984B

 ANODE
 ANODE datasheet pinout or pin assignment. 5. EMITTER Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.

DESCRIPTION: SC-88A (SC-70-5/SOT-353) **PAGE 1 OF 1**

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.



DOCUMENT NUMBER:	98AON13593G	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	UDFN6 1.0X1.0, 0.35P		PAGE 1 OF 1

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

DATE 09 JUN 2021



REFERENCE



A

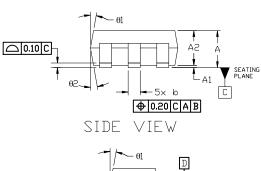
F1 F

В

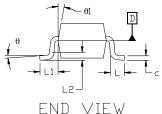


NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 19894
- CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS, MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.25 PER SIDE. D AND E1 DIMENSIONS ARE DETERMINED AT DATUM D.
- DIMENSION 'b' DOES NOT INCLUDE DAMBAR PROTRUSION. DAMBAR PROTRUSION SHALL BE O. 08mm TOTAL IN EXCESS OF THE 'b' DIMENSION AT MAXIMUM MATERIAL CONDITION. MINIMUM SPACE BETWEEN PROTRUSION AND AN ADJACENT LEAD SHALL NOT BE LESS THAN 0.07mm.



TOP VIEW



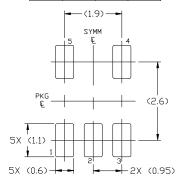
GENERIC MARKING DIAGRAM*



XXX = Specific Device Code = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "=", may or may not be present. Some products may not follow the Generic Marking.

	MILLIMETERS			
DIM	MIN.	N□M.	MAX.	
Α	0.90		1.45	
A1	0.00	_	0.15	
A2	0.90	1.15	1.30	
b	0.30	_	0.50	
_	0.08	_	0.22	
D	2.90 BSC			
Ε	2.80 BSC			
E1	1.60 BSC			
е	0.95 BSC			
L	0.30	0.45	0.60	
L1	0.60 REF			
L2	0.25 REF			
θ	0°	4°	8°	
θ1	0°	10°	15°	
θ2	0°	10°	15°	



RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the $\square N$ Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DOCUMENT NUMBER:	98AON34320E	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	SOT-23, 5 LEAD		PAGE 1 OF 1

ON Semiconductor and unare trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the

onsemi, Onsemi, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <a href="www.onsemi.org/www.onsemi.or

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at www.onsemi.com/support/sales

